

### Description

The AU2521P1 is a 2.5V bi-directional ESD protection diode, utilizing leading monolithic silicon technology to provide fast response time and ultra low ESD clamping voltage, making this device an ideal solution for protecting voltage sensitive data and power line. The AU2521P1 complies with the IEC 61000-4-2 (ESD) with  $\pm 30\text{kV}$  air and  $\pm 30\text{kV}$  contact discharge. It is assembled into an ultra-small 1.0x0.6x0.5mm DFN lead-free package. The small size and high ESD surge protection make AU2521P1 an ideal choice to protect cell phone, digital cameras, audio players and many other portable applications.

### Features

- Protects one data line
- Ultra low leakage: nA level
- Ultra low operating voltage: 2.5V
- Ultra low clamping voltage
- Complies with following standards:
  - IEC 61000-4-2 (ESD) immunity test
    - Air discharge:  $\pm 30\text{kV}$
    - Contact discharge:  $\pm 30\text{kV}$
  - IEC61000-4-5 (Lightning) 10A (8/20 $\mu\text{s}$ )
- RoHS Compliant

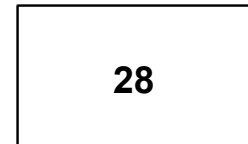
### Mechanical Characteristics

- Package: DFN1006-2 (1.0x0.6x0.5mm)
- Case Material: “Green” Molding Compound.
- Moisture Sensitivity: Level 3 per J-STD-020
- Terminal Connections: See Diagram Below
- Marking Information: See Below

### Applications

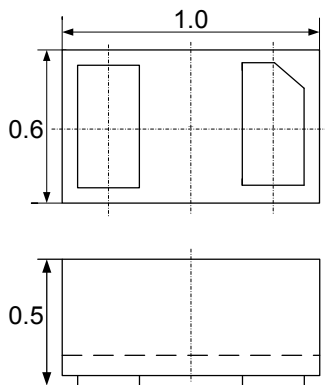
- Cellular Handsets and Accessories
- Personal Digital Assistants
- Notebooks and Handhelds
- Portable Instrumentation
- Digital Cameras
- Peripherals
- Audio Players
- Keypads, Side Keys, LCD Displays

### Marking Information

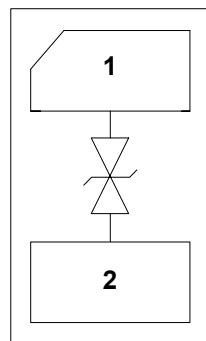


28= Device Marking Code

### Dimensions and Pin Configuration



Package Dimensions



Circuit and Pin Schematic

### Ordering Information

Part Number	Packaging	Reel Size
AU2521P1	10000/Tape & Reel	7 inch

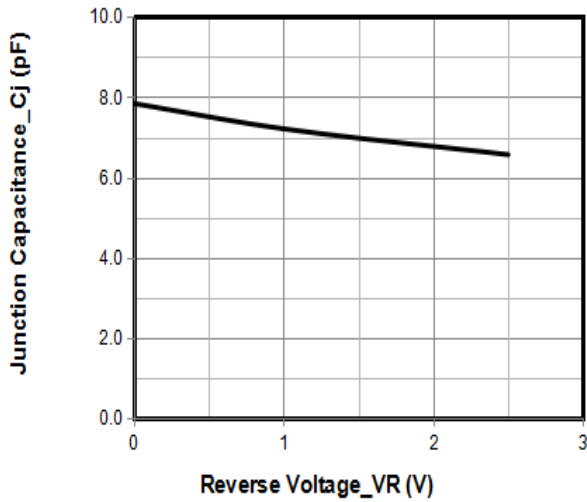
**Absolute Maximum Ratings ( $T_A=25^{\circ}\text{C}$  unless otherwise specified)**

Parameter	Symbol	Value	Unit
Peak Pulse Power (8/20 $\mu\text{s}$ )	Ppk	100	W
Peak Pulse Current (8/20 $\mu\text{s}$ )	Ipp	10	A
ESD per IEC 61000-4-2 (Air)	VESD	$\pm 30$	kV
ESD per IEC 61000-4-2 (Contact)		$\pm 30$	
Operating Temperature Range	TJ	-40 to +85	$^{\circ}\text{C}$
Storage Temperature Range	Tstg	-55 to +150	$^{\circ}\text{C}$

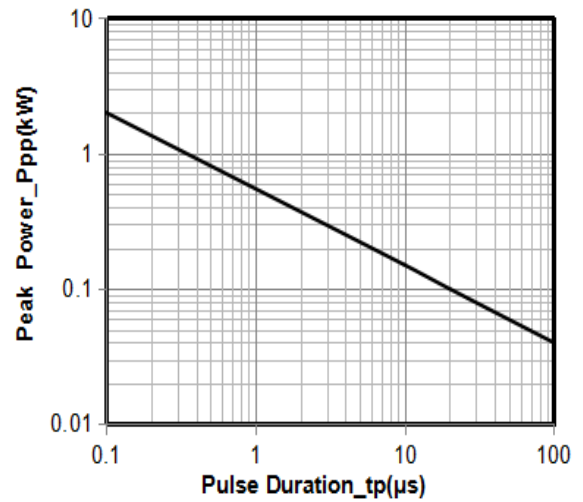
**Electrical Characteristics ( $T_A=25^{\circ}\text{C}$  unless otherwise specified)**

Parameter	Symbol	Min	Typ	Max	Unit	Test Condition
Reverse Working Voltage	VRWM		2.5	2.8	V	
Punch-Through Voltage	VPT	2.9			V	IT = 2 $\mu\text{A}$
Snap-Back Voltage	VSB	2.8			V	IT = 50mA
Reverse Leakage Current	IR			0.1	$\mu\text{A}$	VRWM = 2.5V
Reverse Leakage Current	IR			0.2	$\mu\text{A}$	VRWM = 2.8V
Clamping Voltage	VC			5	V	I <sub>PP</sub> = 1A (8 x 20 $\mu\text{s}$ pulse)
Clamping Voltage	VC			10	V	I <sub>PP</sub> = 10A (8 x 20 $\mu\text{s}$ pulse)
Junction Capacitance	CJ			25	pF	VR = 0V, f = 1MHz

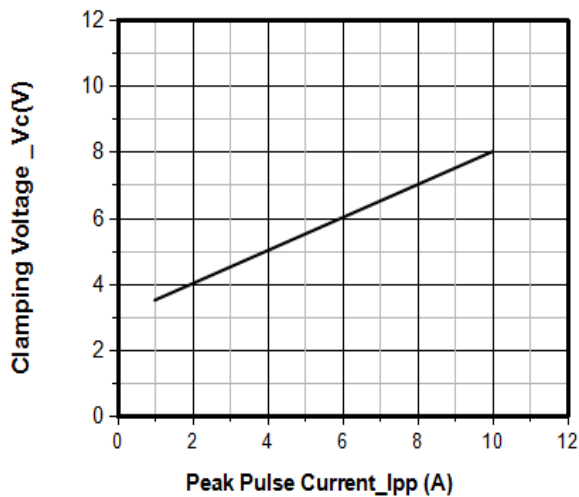
**Typical Performance Characteristics ( $T_A=25^\circ\text{C}$  unless otherwise Specified)**



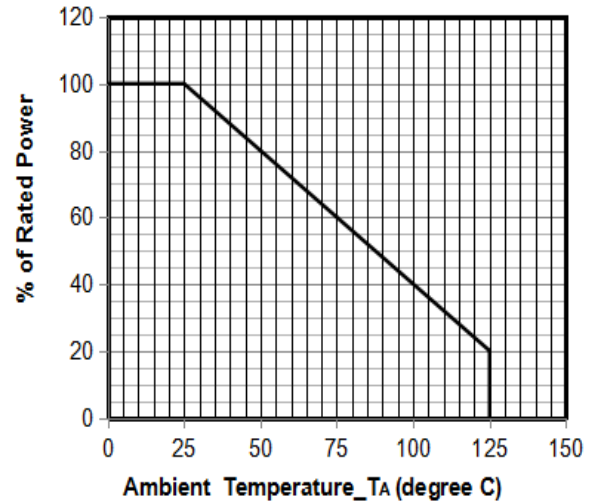
**Junction Capacitance vs. Reverse Voltage**



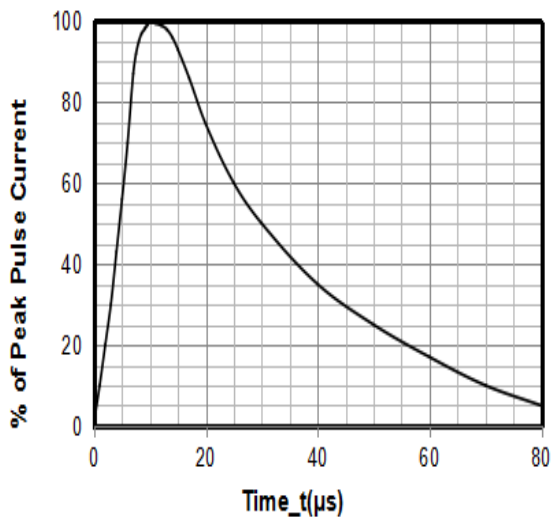
**Peak Pulse Power vs. Pulse Time**



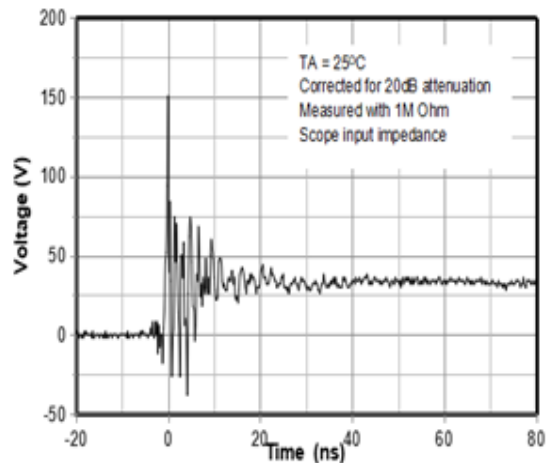
**Clamping Voltage vs. Peak Pulse Current**



**Power Derating Curve**



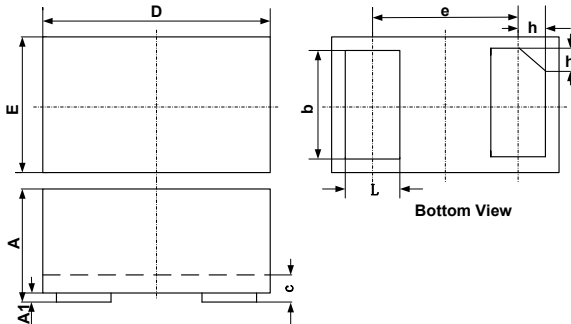
**8 X 20uS Pulse Waveform**



**ESD Clamping Voltage**

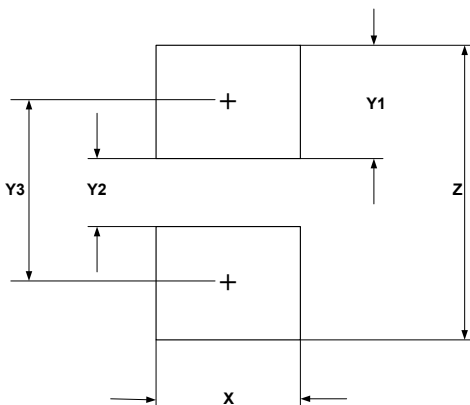
**8 kV Contact per IEC61000-4-2**

### DFN1006-2 Package Outline Drawing



SYM	DIMENSIONS					
	MILLIMETERS			INCHES		
	MIN	NOM	MAX	MIN	NOM	MAX
A	0.45	0.50	0.55	0.018	0.020	0.022
A1	0.00	0.02	0.05	0.000	0.001	0.002
b	0.45	0.50	0.55	0.018	0.020	0.022
c	0.12	0.15	0.18	0.005	0.006	0.007
D	0.95	1.00	1.05	0.037	0.039	0.041
e	0.65 BSC			0.026 BSC		
E	0.55	0.60	0.65	0.022	0.024	0.026
L	0.20	0.25	0.30	0.008	0.010	0.012
h	0.07	0.12	0.17	0.003	0.005	0.007

### Suggested Land Pattern



SYM	DIMENSIONS	
	MILLIMETERS	INCHES
X	0.60	0.024
Y1	0.50	0.020
Y2	0.30	0.012
Y3	0.80	0.032
Z	1.30	0.052

### Contact Information

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单击下面可查看定价，库存，交付和生命周期等信息

[>>APM](#)